NSN 5961-01-078-3617 Thyristor Semiconductor Device - Page 1 of 1



| View Online at https://aerobasegroup.com/nsn/5961-01-078-3617 |
|---|
| Inclosure Material: |
| Glass and metal |
| Overall Length: |
| Between 0.916 inches and 0.936 inches |
| Mounting Facility Quantity: |
| 1 |
| Mounting Method: |
| Threaded stud |
| Features Provided: |
| Hermetically sealed case |
| Overall Width Across Flats: |
| Between 1.052 inches and 1.058 inches |
| Thread Size: |
| 0.500 inches |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 100.0 repetitive peak reverse voltage, peak total value, gate terminal open-circuited |
| Current Rating Per Characteristic: |
| 70.00 amperes forward current, total rms universal |
| Power Rating Per Characteristic: |
| 15.0 watts small-signal input power, common-collector blank |
| Maximum Operating Tempurature Per Measurement Point: |
| 125.0 degrees celsius junction |
| Thread Series Designator: |
| Unf |
| Terminal Type And Quantity: |
| 1 threaded stud and 2 tab, solder lug |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| M110a0 |